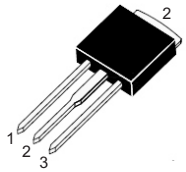
TRIACs, 6A

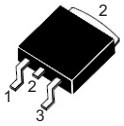
Snubberless, Logic Level and Standard

MAIN FEATURES

SYMBOL	VALUE	UNIT
$I_{T(RMS)}$	6	A
V_{DRM}/V_{RRM}	600 to 1000	V
$I_{GT(Q1)}$	5 to 50	mA



TO-251 **(I-PAK)**
(6TxxF)



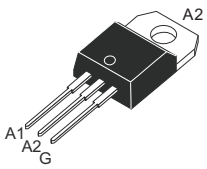
TO-252 **(D-PAK)**
(6TxxG)

DESCRIPTION

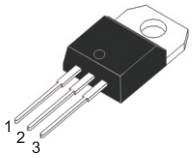
The 6T triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control operation in light dimmers, motor speed controllers,...

The snubberless and logic level versions are specially recommended for use on inductive loads, thanks to their high commutation performances.

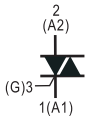
By using an internal ceramic pad, the 6T series provides voltage insulated tab (rated at 2500VRMS) complying with UL standards (File ref. :E320098)



TO-220AB **(non-Insulated)**
(6TxxA)



TO-220AB **(Insulated)**
(6TxxAI)



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**VALUE**	**UNIT**
RMS on-state current (full sine wave)	$I_{T(RMS)}$	TO-251/TO-252/TO-220AB	T_c = 110ºC	6	A
		TO-220AB insulated	T_c = 105ºC		
Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	I_{TSM}	F =50 Hz	t = 20 ms	60	A
		F =60 Hz	t = 16.7 ms	63	
I^2t Value for fusing	I^2t	t_p = 10 ms		21	A^2s
Critical rate of rise of on-state current I_G = 2xI_{GT}, t_r≤100ns	dI/dt	F =100 Hz	T_j =125ºC	50	A/µs
Peak gate current	I_{GM}	T_p =20 µs	T_j =125ºC	4	A
Average gate power dissipation	$P_{G(AV)}$	T_j =125ºC		1	W
Storage temperature range	T_{stg}			- 40 to + 150	ºC
Operating junction temperature range	T_j			- 40 to + 125	

◎ ELECTRICAL CHARACTERISTICS (T_J= 25 ºC unless otherwise specified)

SNUBBERLESS and Logic level (3 quadrants)								
SYMBOL	TEST CONDITIONS	QUADRANT		6Txxxx				Unit
				TW	SW	CW	BW	
I_{GT}(1)	V_D = 12 V, R_L = 30Ω	I - II - III	MAX.	05	10	35	50	mA
V_{GT}		I - II - III	MAX.	1.3				V
V_{GD}	V_D = V_{DRM}, R_L = 3.3KΩ T_j = 125°C	I - II - III	MIN.	0.2				V
I_H(2)	I_T = 200 mA		MAX.	10	15	40	55	mA
I_L	I_G = 1.2 I_{GT}	I - III	MAX.	10	25	50	70	mA
		II		15	30	60	80	
dV/dt(2)	V_D = 67% V_{DRM}, gate open ,T_j = 125°C		MIN.	20	40	400	1000	V/µs
(dI/dt)c(2)	(dV/dt)c = 0.1 V/µs	T_j = 125°C	MIN.	2.7	3.5	-	-	A/ms
	(dV/dt)c = 10 V/µs	T_j = 125°C		1.2	2.4	-	-	
	Without snubber	T_j = 125°C		-	-	3.5	5.3	

◎ ELECTRICAL CHARACTERISTICS (T_J= 25 ºC unless otherwise specified)

Standard (4 quadrants)						
SYMBOL	TEST CONDITIONS	QUADRANT		6Txxxx		UNIT
				C	B	
I_{GT}(1)	V_D = 12 V, R_L = 30Ω	I - II - III	MAX.	25	50	mA
		IV		50	100	
V_{GT}		ALL		1.3		V
V_{GD}	V_D = V_{DRM}, R_L = 3.3KΩ, T_j = 125°C	ALL		0.2		V
I_H(2)	I_T = 200 mA		MAX.	25	50	mA
I_L	I_G = 1.2 I_{GT}	I - III - IV	MAX.	40	50	mA
		II		80	100	
dV/d_t(2)	V_D = 67% V_{DRM}, gate open, T_j = 125°C		MIN.	200	400	V/µs
(dV/dt)c(2)	(dI/dt)c = 2.7 A/ms, T_j = 125°C		MIN.	5	10	V/µs

STATIC CHARACTERISTICS					
SYMBOL	TEST CONDITIONS			VALUE	UNIT
V_{TM}(2)	I_{TM} = 8.5 A, t_P = 380 µs	T_j = 25°C	MAX.	1.55	V
V_{t0}(2)	Threshold voltage	T_j = 125°C	MAX.	0.85	V
R_d(2)	Dynamic resistance	T_j = 125°C	MAX.	60	mΩ
I_{DRM} I_{RRM}	V_{DRM} = V_{RRM}	T_j = 25°C	MAX.	5	µA
		T_j = 125°C		1	mA

Note 1: Minimum I_{GT} is guaranted at 5% of I_{GT} max.
Note 2: For both polarities of A2 referenced to A1.

THERMAL RESISTANCE

SYMBOL			VALUE	UNIT
$R_{th(j-c)}$	Junction to case (AC)	TO-220AB, TO-251, TO-252	1.8	°C/W
		TO-220AB Insulated	2.7	
$R_{th(j-a)}$	Junction to ambient	TO-220AB, TO-251, TO-252	60	°C/W
		TO-220AB Insulated		

PRODUCT SELECTOR

PART NUMBER	VOLTAGE (xx)			SENSITIVITY	TYPE	PACKAGE
	600 V	800 V	1000 V			
6TxxA-B/6TxxAI-B	V	V	V	50 mA	Standard	TO-220AB
6TxxA-BW/6TxxAI-BW	V	V	V	50 mA	Snubberless	TO-220AB
6TxxA-C/6TxxAI-C	V	V	V	25 mA	Standard	TO-220AB
6TxxA-CW/6TxxAI-CW	V	V	V	35 mA	Snubberless	TO-220AB
6TxxA-SW/6TxxAI-SW	V	V	V	10 mA	Logic level	TO-220AB
6TxxA-TW/6TxxAI-TW	V	V	V	5 mA	Logic level	TO-220AB
6TxxF-BW	V	V	V	50 mA	Snubberless	I-PAK
6TxxG-BW	V	V	V	50 mA	Snubberless	D-PAK
6TxxF-CW	V	V	V	35 mA	Snubberless	I-PAK
6TxxG-CW	V	V	V	35 mA	Snubberless	D-PAK
6TxxF-SW	V	V	V	10 mA	Logic level	I-PAK
6TxxG-SW	V	V	V	10 mA	Logic level	D-PAK
6TxxF-B	V	V	V	50 mA	Standard	I-PAK
6TxxG-B	V	V	V	50 mA	Standard	D-PAK
6TxxF-C	V	V	V	25 mA	Standard	I-PAK
6TxxG-C	V	V	V	25 mA	Standard	D-PAK

ORDERING INFORMATION

ORDERING TYPE	MARKING	PACKAGE	WEIGHT	BASE Q'TY	DELIVERY MODE
6TxxA-yy	6TxxA-yy	TO-220AB	2.0g	50	Tube
6TxxAI-yy	6TxxAI-yy	TO-220AB (insulated)	2.3g	50	Tube
6TxxF-yy	6TxxF-yy	TO-251(I-PAK)	0.40g	80	Tube
6TxxG-yy	6TxxG-yy	TO-252(D-PAK)	0.38g	80	Tube

Note: xx = voltage, yy = sensitivity

ORDERING INFORMATION SCHEME

6 T 06 A - BW

Current
6 = 6A

Triac series

Voltage
06 = 600V
08 = 800V
10 = 1000V

Package type
A = TO-220AB (non-insulated)
AI = TO-220AB (insulated)
AF= TO-220F(ISOWAT TO-220AB, insulated)
F = TO-251 (I-PAK)
G = TO-252 (D-PAK)

I_{GT} Sensitivity

B = 50mA Standard	BW = 50mA Snubberless
C = 25mA Standard	CW = 35mA Snubberless
SW = 10mA Logic Level	TW = 5mA Logic Level

Fig.1 Maximum power dissipation versus RMS on-state current (full cycle)

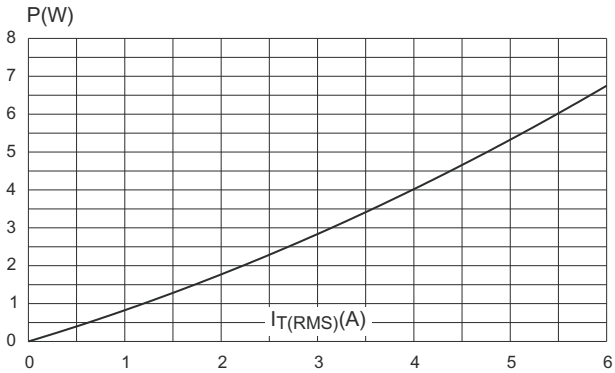


Fig.2 RMS on-state current versus case temperature (full cycle)

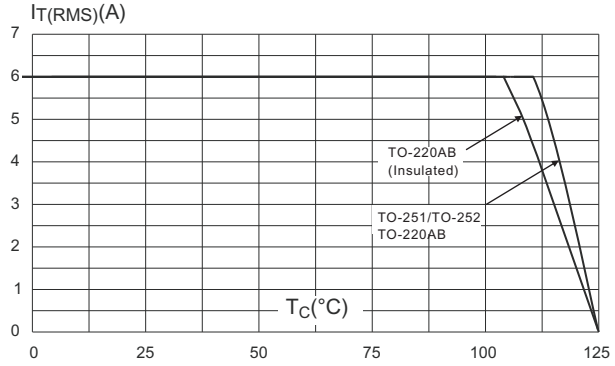


Fig.3 Relative variation of thermal impedance versus pulse duration.

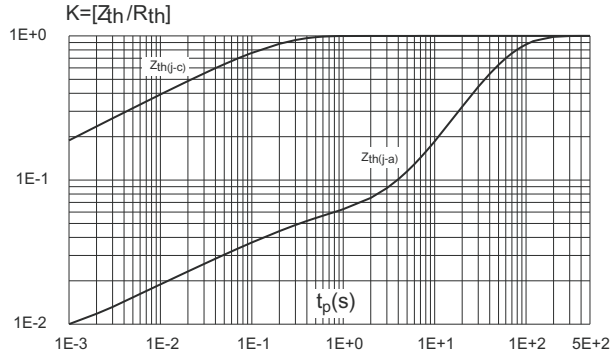


Fig.4 On-state characteristics (maximum values).

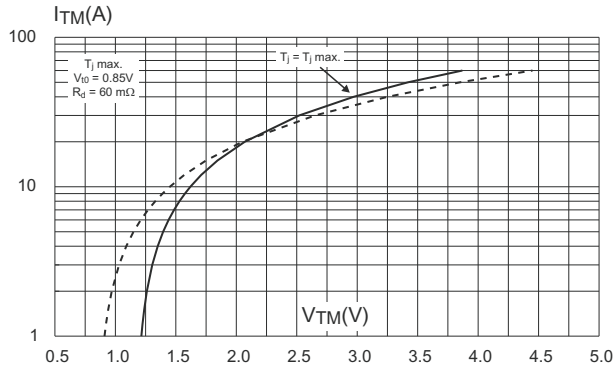


Fig.5 Surge peak on-state current versus number of cycles.

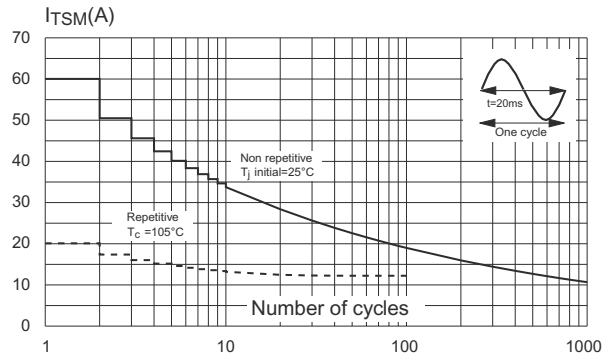


Fig.6 Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10ms. and corresponding value of I^2t.

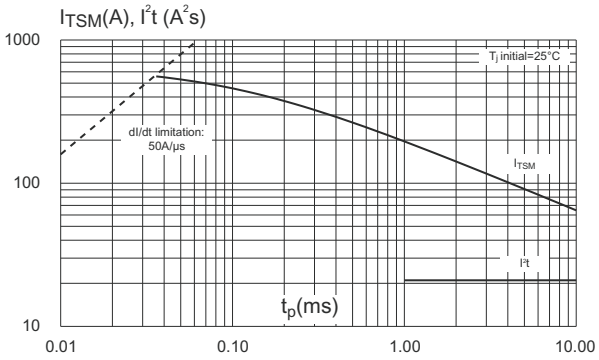


Fig.7 Relative variation of gate trigger current,holding current and latching current versus junction temperature (typical values).

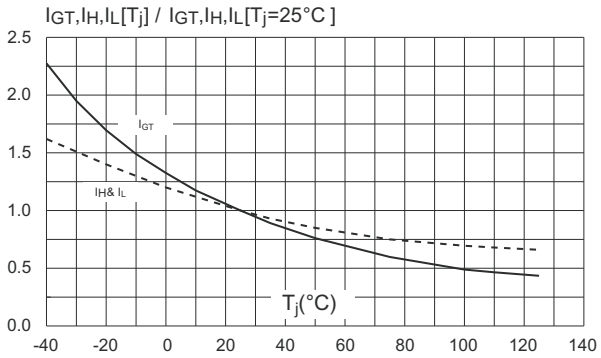


Fig.8 Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values). Snubberless & Logic Level Types

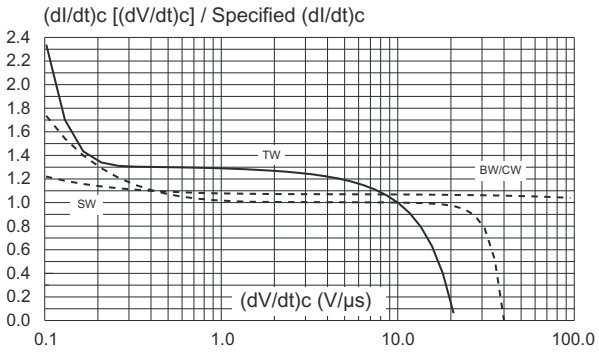


Fig.9 Relative variation of critical rate of decrease of main current versus (dV/dt)C (typical values) (Standard types).

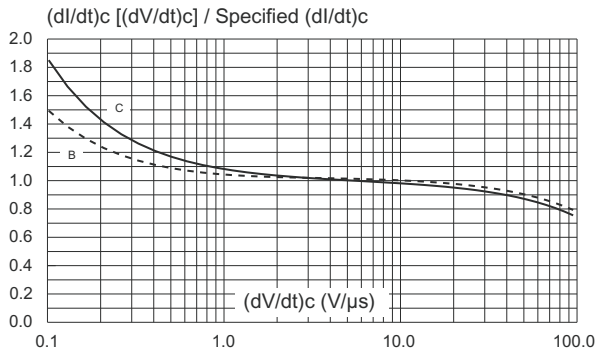
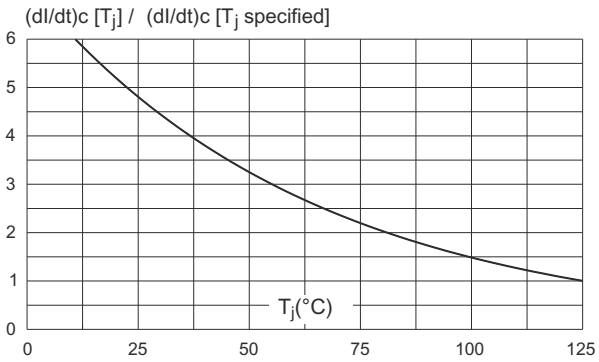
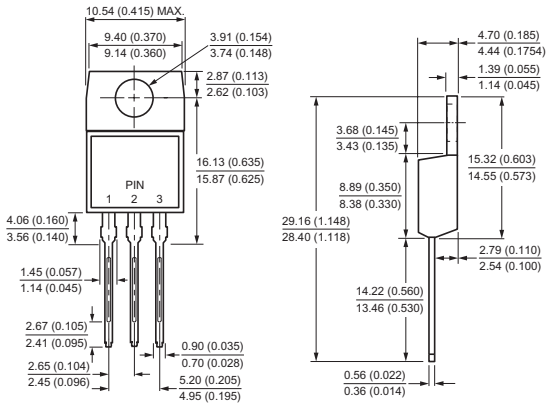


Fig.10 Relative variation of critical rate decrease of main current versus junction temperature .

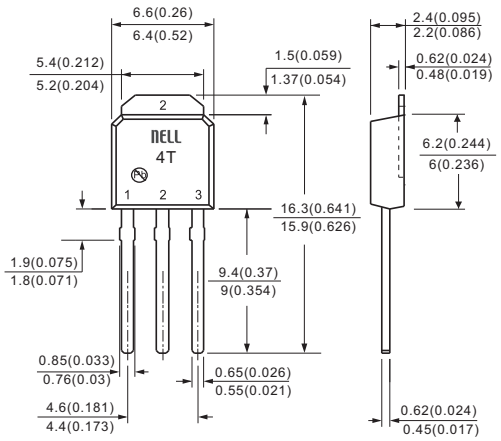


Case Style

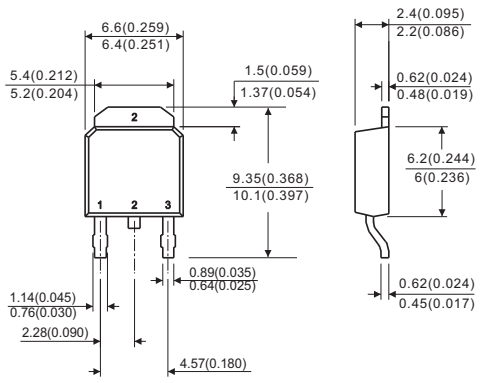
TO-220AB

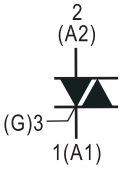


TO-251 (I-PAK)



TO-252 (D-PAK)





All dimensions in millimeters(inches)